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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	AVR
Core Size	32-Bit Single-Core
Speed	66MHz
Connectivity	EBI/EMI, I ² C, IrDA, Memory Card, SPI, SSC, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, POR, WDT
Number of I/O	88
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	1.75V ~ 3.6V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-VFBGA
Supplier Device Package	100-VFBGA (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/atmel/at32uc3a4128-c1ut

- Support for SPI and LIN
- Optionnal support for IrDA, ISO7816, Hardware Handshaking, RS485 interfaces and Modem Line
- Two Master/Slave Serial Peripheral Interfaces (SPI) with Chip Select Signals
- One Synchronous Serial Protocol Controller
 - Supports I2S and Generic Frame-Based Protocols
- Two Master/Slave Two-Wire Interface (TWI), 400 kbit/s I2C-compatible
- 16-bit Stereo Audio Bitstream
 - Sample Rate Up to 50 KHz
- QTouch® Library Support
 - Capacitive Touch Buttons, Sliders, and Wheels
 - QTouch and QMatrix Acquisition
- On-Chip Debug System (JTAG interface)
 - Nexus Class 2+, Runtime Control, Non-Intrusive Data and Program Trace
- 110 General Purpose Input/Output (GPIOs)
 - Standard or High Speed mode
 - Toggle capability: up to 84MHz
- Packages
 - 144-ball TFBGA, 11x11 mm, pitch 0.8 mm
 - 144-pin LQFP, 22x22 mm, pitch 0.5 mm
 - 100-ball VFBGA, 7x7 mm, pitch 0.65 mm
- Single 3.3V Power Supply



3. Package and Pinout

3.1 Package

The device pins are multiplexed with peripheral functions as described in the Peripheral Multiplexing on I/O Line section.

Figure 3-1. TFBGA144 Pinout (top view)

	1	2	3	4	5	6	7	8	9	10	11	12
Α	O PX40	O PB00	O PA28	O PA27	O PB03	O PA29	O PC02	O PC04	O PC05	DPHS	DMHS (JSB_VBUS
В	O PX10	O PB11	O PA31	O PB02	VDDIO	O PB04	O PC03	VDDIO	USB_VBIAS	O DMFS	GNDPLL	PA09
С	O PX09	O PX35	GNDIO	O PB01	O PX16	O PX13	O PA30	O PB08	DPFS	GNDCORE	O PA08	O PA10
D	O PX08	O PX37	O PX36	O PX47	O PX19	O PX12	O PB10	O PA02	O PA26	O PA11	O PB07	O PB06
Е	O PX38	VDDIO	O PX54	O PX53	VDDIO	O PX15	O PB09	VDDIN	O PA25	O PA07	VDDCORE	O PA12
F	O PX39	O PX07	PX06	O PX49	O PX48	GNDIO	GNDIO	O PA06	O PA04	O PA05	O PA13	O PA16
G	O PX00	O PX05	O PX59	O PX50	O PX51	GNDIO	GNDIO	O PA23	O PA24	O PA03	O PA00	O PA01
Н	O PX01	VDDIO	O PX58	O PX57	VDDIO	O PC01	O PA17	VDDIO	O PA21	O PA22	VDDANA	O PB05
J	O PX04	O PX02	O PX34	O PX56	O PX55	O PA14	O PA15	O PA19	O PA20	TMS	TDO	RESET_N
K	O PX03	O PX44	GNDIO	O PX46	PC00	O PX17	O PX52	O PA18	O PX27	GNDIO	O PX29	TCK
L	O PX11	GNDIO	O PX45	O PX20	VDDIO	O PX18	O PX43	VDDIN	O PX26	O PX28	GNDANA	TDI
M	O PX22	O PX41	O PX42	O PX14	O PX21	O PX23	O PX24	O PX25	O PX32	O PX31	PX30	O PX33



Figure 3-3. VFBGA100 Pinout (top view)

_	1	2	3	4	5	6	7	8	9	10
Α	O PA28	O PA27	O PB04	O PA30	O PC02	O PC03	O PC05	O DPHS	DMHS	USB_VBUS
В	O PB00	O PB01	O PB02	O PA29	VDDIO	VDDIO	O PC04	DPFS	DMFS	GNDPLL
С	O PB11	O PA31	GNDIO	PB03	PB09	PB08	USB_VBIAS	GNDIO	O PA11	O PA10
D	O PX12	PX10	O PX13	PX16/ PX53 ⁽¹⁾	O PB10	O PB07	O PB06	PA09	VDDIN	VDDIN
Е	PA02/ PX47 ⁽¹⁾	GNDIO	PX08	PX09	VDDIO	GNDIO	O PA16	PA06/ PA13 ⁽¹⁾	O PA04	VDDCORE
F	PX19/ PX59 ⁽¹⁾	VDDIO	PX06	PX07	GNDIO	VDDIO	PA26/ PB05 ⁽¹⁾	O PA08	PA03	GNDCORE
G	PX05	PX01	O PX02	PX00	O PX30	PA23/ PX46 ⁽¹⁾	PA12/ PA25 ⁽¹⁾	PA00/ PA18 ⁽¹⁾	PA05	PA01/ PA17 ⁽¹⁾
Н	PX04	O PX21	GNDIO	O PX25	O PX31	PA22/ PX20 ⁽¹⁾	TMS	GNDANA	PA20/ PX18 ⁽¹⁾	PA07/ PA19 ⁽¹⁾
J	PX03	O PX24	PX26	PX29	VDDIO	VDDANA	PA15/ PX45 ⁽¹⁾	TDO	RESET_N	PA24/ PX17 ⁽¹⁾
K	O PX23	PX27	PX28	PX15/ PX32 ⁽¹⁾	PC00/ PX14 ⁽¹⁾	PC01	PA14/ PX11 ⁽¹⁾	TDI	TCK	PA21/ PX22 ⁽¹⁾

Note: 1. Those balls are physically connected to 2 GPIOs. Software must managed carrefully the GPIO configuration to avoid electrical conflict



Table 3-6.Signal Description List

Signal Name	Function	Туре	Active Level	Comments
RESET_N	Reset Pin	Input	Low	
	DMA Controller - DMA	ACA (optional)	
DMAACK[1:0]	DMA Acknowledge	Output		
DMARQ[1:0]	DMA Requests	Input		
	External Interrupt Co	ontroller - EIC		
EXTINT[7:0]	External Interrupt Pins	Input		
SCAN[7:0]	Keypad Scan Pins	Output		
NMI	Non-Maskable Interrupt Pin	Input	Low	
	General Purpose Input/Output pin - C	PIOA, GPIOE	, GPIOC, G	PIOX
PA[31:0]	Parallel I/O Controller GPIO port A	I/O		
PB[11:0]	Parallel I/O Controller GPIO port B	I/O		
PC[5:0]	Parallel I/O Controller GPIO port C	I/O		
PX[59:0]	Parallel I/O Controller GPIO port X	I/O		
	External Bus Inte	rface - EBI	1	
ADDR[23:0]	Address Bus	Output		
CAS	Column Signal	Output	Low	
CFCE1	Compact Flash 1 Chip Enable	Output	Low	
CFCE2	Compact Flash 2 Chip Enable	Output	Low	
CFRNW	Compact Flash Read Not Write	Output		
DATA[15:0]	Data Bus	I/O		
NANDOE	NAND Flash Output Enable	Output	Low	
NANDWE	NAND Flash Write Enable	Output	Low	
NCS[5:0]	Chip Select	Output	Low	
NRD	Read Signal	Output	Low	
NWAIT	External Wait Signal	Input	Low	
NWE0	Write Enable 0	Output	Low	
NWE1	Write Enable 1	Output	Low	
RAS	Row Signal	Output	Low	



Table 5-1. AT32UC3A3A4 Physical Memory Map

		Size	Size	Size
Device	Start Address	AT32UC3A3256S AT32UC3A3256 AT32UC3A4256S AT32UC3A4256	AT32UC3A3128S AT32UC3A3128 AT32UC3A4128S AT32UC3A4128	AT32UC3A364S AT32UC3A364 AT32UC3A464S AT32UC3A464
HRAMC0	0xFF000000	32KByte	32KByte	32KByte
HRAMC1	0xFF008000	32KByte	32KByte	32KByte
HSB-PB Bridge A	0xFFFF0000	64KByte	64KByte	64KByte
HSB-PB Bridge B	0xFFFE0000	64KByte	64KByte	64KByte

5.3 Peripheral Address Map

 Table 5-2.
 Peripheral Address Mapping

Address		Peripheral Name
0xFF100000	DMACA	DMA Controller - DMACA
0xFFFD0000	AES	Advanced Encryption Standard - AES
0xFFFE0000	USB	USB 2.0 Device and Host Interface - USB
0xFFFE1000	HMATRIX	HSB Matrix - HMATRIX
0xFFFE1400	FLASHC	Flash Controller - FLASHC
0xFFFE1C00	SMC	Static Memory Controller - SMC
0xFFFE2000	SDRAMC	SDRAM Controller - SDRAMC
0xFFFE2400	ECCHRS	Error code corrector Hamming and Reed Solomon - ECCHRS
0xFFFE2800	BUSMON	Bus Monitor module - BUSMON
0xFFFE4000	MCI	Mulitmedia Card Interface - MCI
0xFFFE8000	MSI	Memory Stick Interface - MSI
0xFFFF0000	PDCA	Peripheral DMA Controller - PDCA
0xFFFF0800	INTC	Interrupt controller - INTC



 Table 5-3.
 Local Bus Mapped GPIO Registers

Port	Register	Mode	Local Bus Address	Access
2	Output Driver Enable Register (ODER)	WRITE	0x40000240	Write-only
		SET	0x40000244	Write-only
		CLEAR	0x40000248	Write-only
		TOGGLE	0x4000024C	Write-only
	Output Value Register (OVR)	WRITE	0x40000250	Write-only
		SET	0x40000254	Write-only
		CLEAR	0x40000258	Write-only
		TOGGLE	0x4000025C	Write-only
	Pin Value Register (PVR)	-	0x40000260	Read-only
3	Output Driver Enable Register (ODER)	WRITE	0x40000340	Write-only
		SET	0x40000344	Write-only
		CLEAR	0x40000348	Write-only
		TOGGLE	0x4000034C	Write-only
	Output Value Register (OVR)	WRITE	0x40000350	Write-only
		SET	0x40000354	Write-only
		CLEAR	0x40000358	Write-only
		TOGGLE	0x4000035C	Write-only
	Pin Value Register (PVR)	-	0x40000360	Read-only

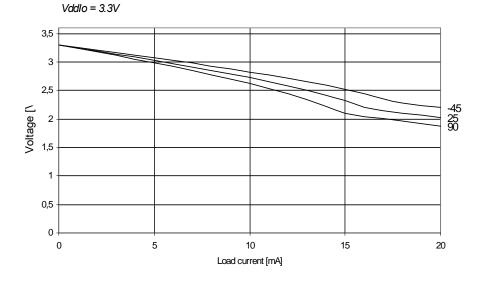


7.2.1 I/O Pin Output Level Typical Characteristics

VddIo = 3.3V1,8 90 1,6 25 1,4 1,2 Voltage [\ 0,8 0,6 0,4 0,2 0 5 10 15 20 Load current [mA]

Figure 7-1. I/O Pin drive x2 Output Low Level Voltage (VOL) vs. Source Current

Figure 7-2. I/O Pin drive x2 Output High Level Voltage (VOH) vs. Source Current



7.3 I/O pin Characteristics

These parameters are given in the following conditions:

- V_{DDCORE} = 1.8V
- $V_{DDIO} = 3.3V$
- Ambient Temperature = 25°C



Table 7-9.BOD Timing

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
T _{BOD}	Minimum time with VDDCORE < VBOD to detect power failure	Falling VDDCORE from 1.8V to 1.1V		300	800	ns

7.5.3 Reset Sequence

 Table 7-10.
 Electrical Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
$V_{\rm DDRR}$	VDDIN/VDDIO rise rate to ensure power-on-reset		0.8			V/ms
V _{POR+}	Rising threshold voltage: voltage up to which device is kept under reset by POR on rising VDDIN	Rising VDDIN: V _{RESTART} -> V _{POR+}		2.7		V
V _{POR} -	Falling threshold voltage: voltage when POR resets device on falling VDDIN	Falling VDDIN: 3.3V -> V _{POR-}		2.7		V
V _{RESTART}	On falling VDDIN, voltage must go down to this value before supply can rise again to ensure reset signal is released at V _{POR+}	Falling VDDIN: 3.3V -> V _{RESTART}			0.2	V
T _{SSU1}	Time for Cold System Startup: Time for CPU to fetch its first instruction (RCosc not calibrated)		480		960	μs
T _{SSU2}	Time for Hot System Startup: Time for CPU to fetch its first instruction (RCosc calibrated)			420		μs



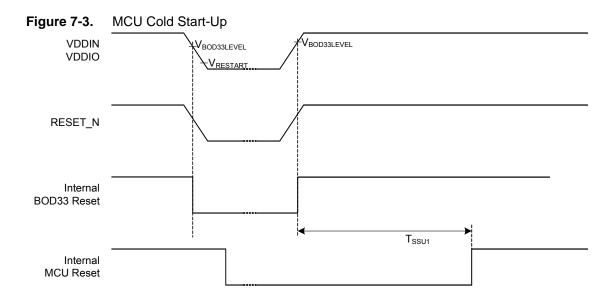


Figure 7-4. MCU Cold Start-Up RESET_N Externally Driven

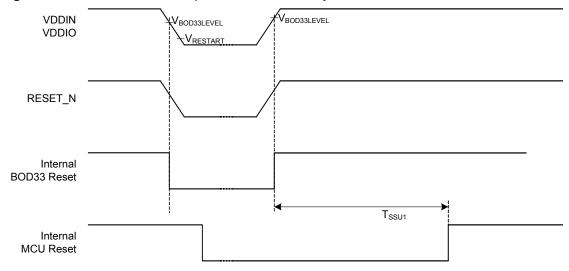


Figure 7-5. MCU Hot Start-Up

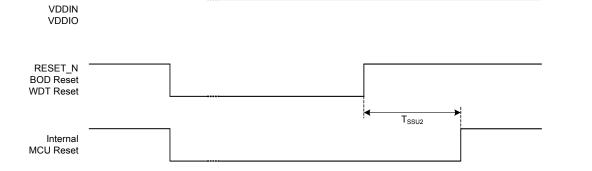




 Table 7-13.
 Typical Cuurent Consumption by Peripheral

Peripheral	Тур.	Unit
ADC	7	
AES	80	
ABDAC	10	
DMACA	70	
EBI	23	
EIC	0.5	
GPIO	37	
INTC	3	
MCI	40	
MSI	10	
PDCA	20	μΑ/MHz
SDRAM	5	μΑ/Ινίπ2
SMC	9	
SPI	6	
SSC	10	
RTC	5	
TC	8	
TWIM	2	
TWIS	2	
USART	10	
USBB	90	
WDT	2	

7.8 Oscillator Characteristics

The following characteristics are applicable to the operating temperature range: $T_A = -40$ °C to 85°C and worst case of power supply, unless otherwise specified.

7.8.1 Slow Clock RC Oscillator

 Table 7-17.
 RC Oscillator Frequency

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
	Calibration point: T _A = 85°C		115.2	116	KHz	
F _{RC}		T _A = 25°C		112		KHz
		T _A = -40°C	105	108		KHz

7.8.2 32 KHz Oscillator

Table 7-18. 32 KHz Oscillator Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
4 //+	Ossillator Fraguenay	External clock on XIN32			30	MHz
1/(t _{CP32KHz})	Oscillator Frequency	Crystal		32 768		Hz
C _L	Equivalent Load Capacitance		6		12.5	pF
ESR	Crystal Equivalent Series Resistance				100	ΚΩ
t _{ST}	Startup Time	$C_L = 6pF^{(1)}$ $C_L = 12.5pF^{(1)}$			600 1200	ms
t _{CH}	XIN32 Clock High Half-period		0.4 t _{CP}		0.6 t _{CP}	
t _{CL}	XIN32 Clock Low Half-period		0.4 t _{CP}		0.6 t _{CP}	
C _{IN}	XIN32 Input Capacitance				5	pF
	0	Active mode			1.8	μA
losc	Current Consumption	Standby mode			0.1	μA

Note: 1. C_L is the equivalent load capacitance.



7.9 ADC Characteristics

Table 7-22. Channel Conversion Time and ADC Clock

Parameter	Conditions	Min.	Тур.	Max.	Unit
ADC Clark Fraguency	10-bit resolution mode			5	MHz
ADC Clock Frequency	8-bit resolution mode			8	MHz
Startup Time	Return from Idle Mode			20	μs
Track and Hold Acquisition Time		600			ns
Conversion Time	ADC Clock = 5 MHz			2	μs
Conversion Time	ADC Clock = 8 MHz			1.25	μs
Throughput Data	ADC Clock = 5 MHz			384 ⁽¹⁾	kSPS
Throughput Rate	ADC Clock = 8 MHz			533 ⁽²⁾	kSPS

- 1. Corresponds to 13 clock cycles: 3 clock cycles for track and hold acquisition time and 10 clock cycles for conversion.
- 2. Corresponds to 15 clock cycles: 5 clock cycles for track and hold acquisition time and 10 clock cycles for conversion.

 Table 7-23.
 ADC Power Consumption

Parameter	Conditions	Min.	Тур.	Max.	Unit
Current Consumption on VDDANA (1)	On 13 samples with ADC clock = 5 MHz			1.25	mA

1. Including internal reference input current

Table 7-24. Analog Inputs

Parameter	Conditions	Min.	Тур.	Max.	Unit
Input Voltage Range		0		VDDANA	٧
Input Leakage Current				1	μΑ
Input Capacitance			7		pF
Input Resistance			350	850	Ohm

Table 7-25. Transfer Characteristics in 8-bit mode

Parameter	Conditions	Min.	Тур.	Max.	Unit	
Resolution			8		Bit	
Abachuta Accuracy	ADC Clock = 5 MHz			0.8	LSB	
Absolute Accuracy	ADC Clock = 8 MHz			1.5	LSB	
Integral New linearity	ADC Clock = 5 MHz		0.35	0.5	LSB	
Integral Non-linearity	ADC Clock = 8 MHz		0.5	1.5	LSB	
D''' (C.11) (C. 12)	ADC Clock = 5 MHz		0.3	0.5	LSB	
Differential Non-linearity	ADC Clock = 8 MHz		0.5	1.5	LSB	
Offset Error	ADC Clock = 5 MHz	-1.5		1.5	LSB	
Gain Error	ADC Clock = 5 MHz	-0.5		0.5	LSB	



 Table 7-32.
 SMC Read Signals with no Hold Settings

Symbol	Parameter	Min.	Unit			
	NRD Controlled (READ_MODE = 1)					
SMC ₁₉	Data Setup before NRD High	13.7	ns			
SMC ₂₀	Data Hold after NRD High	1	ns			
	NRD Controlled (READ_MODE = 0)					
SMC ₂₁	Data Setup before NCS High	13.3	ns			
SMC ₂₂	Data Hold after NCS High	0	ns			

 Table 7-33.
 SMC Write Signals with Hold Settings

Symbol	Parameter	Min.	Unit					
	NRD Controlled (READ_MODE = 1)							
SMC ₂₃	Data Out Valid before NWE High	(nwe pulse length - 1) * t _{CPSMC} - 0.9	ns					
SMC ₂₄	Data Out Valid after NWE High ⁽¹⁾	nwe hold length * t _{CPSMC} - 6	ns					
SMC ₂₅	NWE High to NBS0/A0 Change ⁽¹⁾	nwe hold length * t _{CPSMC} - 1.9	ns					
SMC ₂₆	NWE High to NBS1 Change ⁽¹⁾	nwe hold length * t _{CPSMC} - 1.9	ns					
SMC ₂₉	NWE High to A1 Change ⁽¹⁾	nwe hold length * t _{CPSMC} - 1.9	ns					
SMC ₃₁	NWE High to A2 - A23 Change ⁽¹⁾	nwe hold length * t _{CPSMC} - 1.7	ns					
SMC ₃₂	NWE High to NCS Inactive ⁽¹⁾	(nwe hold length - ncs wr hold length)* t _{CPSMC} - 2.9	ns					
SMC ₃₃	NWE Pulse Width	nwe pulse length * t _{CPSMC} - 0.9	ns					
	NRD Controlle	ed (READ_MODE = 0)						
SMC ₃₄	Data Out Valid before NCS High	(ncs wr pulse length - 1)* t _{CPSMC} - 4.6	ns					
SMC ₃₅	Data Out Valid after NCS High ⁽¹⁾	ncs wr hold length * t _{CPSMC} - 5.8	ns					
SMC ₃₆	NCS High to NWE Inactive ⁽¹⁾	(ncs wr hold length - nwe hold length)* t _{CPSMC} - 0.6	ns					

Note: 1. hold length = total cycle duration - setup duration - pulse duration. "hold length" is for "ncs wr hold length" or "nwe hold length"

 Table 7-34.
 SMC Write Signals with No Hold Settings (NWE Controlled only)

Symbol	Parameter	Min.	Unit
SMC ₃₇	NWE Rising to A2-A25 Valid	5.4	ns
SMC ₃₈	NWE Rising to NBS0/A0 Valid	5	ns
SMC ₃₉	NWE Rising to NBS1 Change	5	ns
SMC ₄₀	NWE Rising to A1/NBS2 Change	5	ns
SMC ₄₁	NWE Rising to NBS3 Change	5	ns
SMC ₄₂	NWE Rising to NCS Rising	5.1	ns



 Table 7-36.
 SDRAM Clock Signal

Symbol	Parameter	Conditions	Min.	Max.	Unit
SDRAMC ₁₃	Bank Change before SDCK Rising Edge		6.3		ns
SDRAMC ₁₄	Bank Change after SDCK Rising Edge		2.4		ns
SDRAMC ₁₅	CAS Low before SDCK Rising Edge		7.4		ns
SDRAMC ₁₆	CAS High after SDCK Rising Edge		1.9		ns
SDRAMC ₁₇	DQM Change before SDCK Rising Edge		6.4		ns
SDRAMC ₁₈	DQM Change after SDCK Rising Edge		2.2		ns
SDRAMC ₁₉	D0-D15 in Setup before SDCK Rising Edge		9		ns
SDRAMC ₂₀	D0-D15 in Hold after SDCK Rising Edge		0		ns
SDRAMC ₂₃	SDWE Low before SDCK Rising Edge		7.6		ns
SDRAMC ₂₄	SDWE High after SDCK Rising Edge		1.8		ns
SDRAMC ₂₅	D0-D15 Out Valid before SDCK Rising Edge		7.1		ns
SDRAMC ₂₆	D0-D15 Out Valid after SDCK Rising Edge		1.5		ns



9. Ordering Information

Device	Ordering Code	Package	Conditioning	Temperature Operating Range
AT32UC3A3256S	AT32UC3A3256S-ALUT	144-lead LQFP	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3256S-ALUR	144-lead LQFP	Reels	Industrial (-40·C to 85·C)
	AT32UC3A3256S-CTUT	144-ball TFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3256S-CTUR	144-ball TFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A3256	AT32UC3A3256-ALUT	144-lead LQFP	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3256-ALUR	144-lead LQFP	Reels	Industrial (-40·C to 85·C)
	AT32UC3A3256-CTUT	144-ball TFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3256-CTUR	144-ball TFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A3128S	AT32UC3A3128S-ALUT	144-lead LQFP	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3128S-ALUR	144-lead LQFP	Reels	Industrial (-40·C to 85·C)
	AT32UC3A3128S-CTUT	144-ball TFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3128S-CTUR	144-ball TFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A3128	AT32UC3A3128-ALUT	144-lead LQFP	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3128-ALUR	144-lead LQFP	Reels	Industrial (-40·C to 85·C)
	AT32UC3A3128-CTUT	144-ball TFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A3128-CTUR	144-ball TFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A364S	AT32UC3A364S-ALUT	144-lead LQFP	Tray	Industrial (-40·C to 85·C)
	AT32UC3A364S-ALUR	144-lead LQFP	Reels	Industrial (-40·C to 85·C)
	AT32UC3A364S-CTUT	144-ball TFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A364S-CTUR	144-ball TFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A364	AT32UC3A364-ALUT	144-lead LQFP	Tray	Industrial (-40·C to 85·C)
	AT32UC3A364-ALUR	144-lead LQFP	Reels	Industrial (-40·C to 85·C)
	AT32UC3A364-CTUT	144-ball TFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A364-CTUR	144-ball TFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A4256S	AT32UC3A4256S-C1UT	100-ball VFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A4256S-C1UR	100-ball VFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A4256	AT32UC3A4256-C1UT	100-ball VFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A4256-C1UR	100-ball VFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A4128S	AT32UC3A4128S-C1UT	100-ball VFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A4128S-C1UR	100-ball VFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A4128	AT32UC3A4128-C1UT	100-ball VFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A4128-C1UR	100-ball VFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A464S	AT32UC3A464S-C1UT	100-ball VFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A464S-C1UR	100-ball VFBGA	Reels	Industrial (-40·C to 85·C)
AT32UC3A464	AT32UC3A464-C1UT	100-ball VFBGA	Tray	Industrial (-40·C to 85·C)
	AT32UC3A464-C1UR	100-ball VFBGA	Reels	Industrial (-40·C to 85·C)



Fix/Workaround

Set to 1b bit CORRS4 of the ECCHRS mode register (MD). In C-code: *((volatile int*) (0xFFFE2404))= 0x400.

DMACA data transfer fails when CTLx.SRC_TR_WIDTH is not equal to CTLx.DST TR WIDTH

Fix/Workaround

For any DMACA transfer make sure CTLx.SRC_TR_WIDTH = CTLx.DST_TR_WIDTH.

3.3V supply monitor is not available

FGPFRLO[30:29] are reserved and should not be used by the application.

Fix/Workaround

None.

Service access bus (SAB) can not access DMACA registers

Fix/Workaround

None.

10.2.2 Processor and Architecture

LDM instruction with PC in the register list and without ++ increments Rp

For LDM with PC in the register list: the instruction behaves as if the ++ field is always set, ie the pointer is always updated. This happens even if the ++ field is cleared. Specifically, the increment of the pointer is done in parallel with the testing of R12.

Fix/Workaround

None.

Hardware breakpoints may corrupt MAC results

Hardware breakpoints on MAC instructions may corrupt the destination register of the MAC instruction.

Fix/Workaround

Place breakpoints on earlier or later instructions.

When the main clock is RCSYS, TIMER CLOCK5 is equal to PBA clock

When the main clock is generated from RCSYS, TIMER_CLOCK5 is equal to PBA Clock and not PBA Clock / 128.

Fix/Workaround

None.

10.2.3 MPU

Privilege violation when using interrupts in application mode with protected system stack

If the system stack is protected by the MPU and an interrupt occurs in application mode, an MPU DTLB exception will occur.

Fix/Workaround

Make a DTLB Protection (Write) exception handler which permits the interrupt request to be handled in privileged mode.

10.2.4 USB

UPCFGn.INTFRQ is irrelevant for isochronous pipe

As a consequence, isochronous IN and OUT tokens are sent every 1ms (Full Speed), or every 125uS (High Speed).



Fix/Workaround

Before going to sleep modes where the system RC oscillator is stopped, make sure that the factor between the CPU/HSB and PBx frequencies is less than or equal to 4.

10.2.9 PDCA

PCONTROL.CHxRES is non-functional

PCONTROL.CHxRES is non-functional. Counters are reset at power-on, and cannot be reset by software.

Fix/Workaround

Software needs to keep history of performance counters.

Transfer error will stall a transmit peripheral handshake interface

If a transfer error is encountered on a channel transmitting to a peripheral, the peripheral handshake of the active channel will stall and the PDCA will not do any more transfers on the affected peripheral handshake interface.

Fix/Workaround

Disable and then enable the peripheral after the transfer error.

10.2.10 AES

URAD (Unspecified Register Access Detection Status) does not detect read accesses to the write-only KEYW[5..8]R registers

Fix/Workaround

None.

10.2.11 HMATRIX

In the PRAS and PRBS registers, the MxPR fields are only two bits

In the PRAS and PRBS registers, the MxPR fields are only two bits wide, instead of four bits. The unused bits are undefined when reading the registers.

Fix/Workaround

Mask undefined bits when reading PRAS and PRBS.

10.2.12 TWIM

TWIM SR.IDLE goes high immediately when NAK is received

When a NAK is received and there is a non-zero number of bytes to be transmitted, SR.IDLE goes high immediately and does not wait for the STOP condition to be sent. This does not cause any problem just by itself, but can cause a problem if software waits for SR.IDLE to go high and then immediately disables the TWIM by writing a one to CR.MDIS. Disabling the TWIM causes the TWCK and TWD pins to go high immediately, so the STOP condition will not be transmitted correctly.

Fix/Workaround

If possible, do not disable the TWIM. If it is absolutely necessary to disable the TWIM, there must be a software delay of at least two TWCK periods between the detection of SR.IDLE==1 and the disabling of the TWIM.

TWIM TWALM polarity is wrong

The TWALM signal in the TWIM is active high instead of active low.

Fix/Workaround

Use an external inverter to invert the signal going into the TWIM. When using both TWIM and TWIS on the same pins, the TWALM cannot be used.



SMBALERT bit may be set after reset

The SMBus Alert (SMBALERT) bit in the Status Register (SR) might be erroneously set after system reset.

Fix/Workaround

After system reset, clear the SR.SMBALERT bit before commencing any TWI transfer.

10.2.13 TWIS

Clearing the NAK bit before the BTF bit is set locks up the TWI bus

When the TWIS is in transmit mode, clearing the NAK Received (NAK) bit of the Status Register (SR) before the end of the Acknowledge/Not Acknowledge cycle will cause the TWIS to attempt to continue transmitting data, thus locking up the bus.

Fix/Workaround

Clear SR.NAK only after the Byte Transfer Finished (BTF) bit of the same register has been set.

TWIS stretch on Address match error

When the TWIS stretches TWCK due to a slave address match, it also holds TWD low for the same duration if it is to be receiving data. When TWIS releases TWCK, it releases TWD at the same time. This can cause a TWI timing violation.

Fix/Workaround

None.

10.2.14 MCI

MCI_CLK features is not available on PX12, PX13 and PX40

Fix/Workaround

MCI CLK feature is available on PA27 only.

The busy signal of the responses R1b is not taken in account for CMD12 STOP_TRANSFER

It is not possible to know the busy status of the card during the response (R1b) for the commands CMD12.

Fix/Workaround

The card busy line should be polled through the GPIO Input Value register (IVR) for commands CMD12.

10.2.15 SSC

Frame Synchro and Frame Synchro Data are delayed by one clock cycle

The frame synchro and the frame synchro data are delayed from 1 SSC_CLOCK when:

- Clock is CKDIV
- The START is selected on either a frame synchro edge or a level
- Frame synchro data is enabled
- Transmit clock is gated on output (through CKO field)

Fix/Workaround

Transmit or receive CLOCK must not be gated (by the mean of CKO field) when START condition is performed on a generated frame synchro.



10.2.16 FLASHC

Corrupted read in flash may happen after fuses write or erase operations (FLASHC LP, UP, WGPB, EGPB, SSB, PGPFB, EAGPF commands)

After a flash fuse write or erase operation (FLASHC LP, UP, WGPB, EGPB, SSB, PGPFB, EAGPF commands), reading (data read or code fetch) in flash may fail. This may lead to an exception or to other errors derived from this corrupted read access.

Fix/Workaround

Before the flash fuse write or erase operation, enable the flash high speed mode (FLASHC HSEN command). The flash fuse write or erase operations (FLASHC LP, UP, WGPB, EGPB, SSB, PGPFB, EAGPF commands) must be issued from RAM or through the EBI. After these commands, read 3 times one flash page initialized to 00h. Disable the flash high speed mode (FLASHC HSDIS command). It is then possible to safely read or code fetch the flash.

10.3 Rev. D

10.3.1 General

Devices cannot operate with CPU frequency higher than 66MHz in 1WS and 36MHz in 0WS

Fix/Workaround

None

DMACA data transfer fails when CTLx.SRC_TR_WIDTH is not equal to CTLx.DST TR WIDTH

Fix/Workaround

For any DMACA transfer make sure CTLx.SRC TR WIDTH = CTLx.DST TR WIDTH.

3.3V supply monitor is not available

FGPFRLO[30:29] are reserved and should not be used by the application.

Fix/Workaround

None.

Service access bus (SAB) can not access DMACA registers

Fix/Workaround

None.

10.3.2 Processor and Architecture

LDM instruction with PC in the register list and without ++ increments Rp

For LDM with PC in the register list: the instruction behaves as if the ++ field is always set, ie the pointer is always updated. This happens even if the ++ field is cleared. Specifically, the increment of the pointer is done in parallel with the testing of R12.

Fix/Workaround

None.

Hardware breakpoints may corrupt MAC results

Hardware breakpoints on MAC instructions may corrupt the destination register of the MAC instruction.

Fix/Workaround

Place breakpoints on earlier or later instructions.



Fix/Workaround

None.

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The busy signal of the responses R1b is not taken in account for CMD12 STOP TRANSFER

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